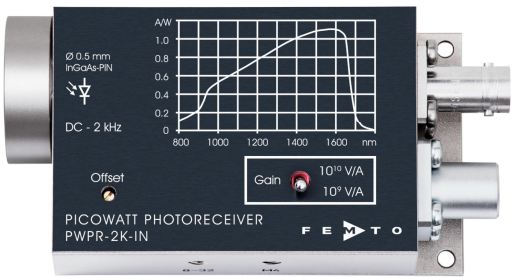






Ultra-Low Noise 2 kHz Photoreceiver
with InGaAs-PIN Photodiode



Features	<ul style="list-style-type: none">• InGaAs-PIN photodiode, 0.5 mm active diameter• Bandwidth DC – 2 kHz• Amplifier transimpedance gain switchable 1.0 × 10⁹ V/A, 1.0 × 10¹⁰ V/A• Spectral range 900 – 1700 nm• Ultra-low noise, NEP 10 fW/√Hz• Free-space input 1.035"-40 threaded, easily convertible to fiber optic input (FC and FSMA) with optionally available screw-on adapters• UNC 8-32 and M4 tapped holes for mounting on standard posts with metric and imperial thread
Applications	<ul style="list-style-type: none">• Spectroscopy, reflection and transmission measurements• Highly sensitive optoelectronic measurements• Applications utilizing optical chopper modulation• Optical front-end for oscilloscopes, A/D converters and lock-in amplifiers
Block Diagram	<div><p>BS01-PWPR_R01</p></div>
Intended Use	<p>The PWPR-2K-IN is a ultra-low noise variable gain photoreceiver. It is designed for fast and precise conversion of small optical signals into equivalent output voltages. Operation is mostly self-explanatory. If in doubt, consult this document or contact support@femto.de.</p> <p>For safe operation, please refer to the damage thresholds specified in the "Absolute Maximum Ratings", "Temperature Range" and "Power Supply" sections of this document.</p> <p>The operating environment must be free of smoke, dust, grease, oil, condensing moisture, and other contaminants that could affect the operation or performance.</p>

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Available Version	<p>PWPR-2K-IN-FST</p>  <p>1.035"-40 threaded flange with internally threaded coupler ring (outer diameter 30 mm) for free space applications, compatible with many optical standard accessories</p> <p>Optionally available: Fiber adapters PRA-FC, PRA-FCA and PRA-FSMA, with the relative large 0.5 mm dia. photodiode installed in the PWPR-2K-IN input coupling is not critical, however, standard SM 9/125 fibers (PC or APC) with low numerical aperture (NA) are recommended for ensuring near 100% coupling efficiency</p>										
Related Model	<p>PWPR-2K-SI-FST</p> <p>Si-PIN, \varnothing 1.2 mm, 320 - 1060 nm free space input, 1.035"-40 threaded flange</p>										
Available Accessories	<div> <p>PRA-FC PRA-FCA PRA-FSMA</p>  <p>Fiber-adapter with external 1.035"-40 thread (suitable for FST models only)</p> </div> <div> <p>PRA-PAP</p>  <p>Alternative mounting option: post adapter plate, easy to mount on FEMTO photoreceiver series OE, FWPR, PWPR, HCA-S and LCA-S</p> </div> <div> <p>PS-15-25-L</p>  <p>Power Supply input: 100 – 240 VAC output: ± 15 VDC</p> </div>										
Specifications	<table> <tr> <td>Test conditions</td><td>$V_s = \pm 15$ V, $T_A = 25$ °C, output load impedance 1 MΩ, warm-up 20 minutes (min. 10 minutes recommended)</td></tr> <tr> <td>Gain</td><td> <p>Transimpedance gain</p> <p>Gain accuracy</p> <p>Conversion gain</p> <p>1.0 $\times 10^9$ V/A, 1.0 $\times 10^{10}$ V/A, switchable (@ output load ≥ 100 kΩ)</p> <p>± 1 % (electrical)</p> <p>1.1 $\times 10^9$ V/W, 1.1 $\times 10^{10}$ V/W typ. (@ 1580 nm, output load ≥ 100 kΩ)</p> </td></tr> <tr> <td>Frequency Response</td><td> <p>Lower cut-off frequency</p> <p>Upper cut-off frequency (–3 dB)</p> <p>DC</p> <p>2 kHz</p> </td></tr> <tr> <td>Time Response</td><td> <p>Rise/fall time (10 % – 90 %)</p> <p>165 μs</p> </td></tr> <tr> <td>Input</td><td> <p>Input offset current (dark current)</p> <p>Input offset current drift</p> <p>Input offset compensation range</p> <p>Optical saturation power</p> <p>NEP</p> <p>0.6 pA typ. factor 2 / 10 °C</p> <p>± 120 pA (adjustable by offset potentiometer)</p> <p>9.1 nW (@ 10⁹ V/A, 1580 nm) 0.91 nW (@ 10¹⁰ V/A, 1580 nm)</p> <p>10 fW/$\sqrt{\text{Hz}}$ (@ 1580 nm, 100 Hz)</p> </td></tr> </table>	Test conditions	$V_s = \pm 15$ V, $T_A = 25$ °C, output load impedance 1 M Ω , warm-up 20 minutes (min. 10 minutes recommended)	Gain	<p>Transimpedance gain</p> <p>Gain accuracy</p> <p>Conversion gain</p> <p>1.0 $\times 10^9$ V/A, 1.0 $\times 10^{10}$ V/A, switchable (@ output load ≥ 100 kΩ)</p> <p>± 1 % (electrical)</p> <p>1.1 $\times 10^9$ V/W, 1.1 $\times 10^{10}$ V/W typ. (@ 1580 nm, output load ≥ 100 kΩ)</p>	Frequency Response	<p>Lower cut-off frequency</p> <p>Upper cut-off frequency (–3 dB)</p> <p>DC</p> <p>2 kHz</p>	Time Response	<p>Rise/fall time (10 % – 90 %)</p> <p>165 μs</p>	Input	<p>Input offset current (dark current)</p> <p>Input offset current drift</p> <p>Input offset compensation range</p> <p>Optical saturation power</p> <p>NEP</p> <p>0.6 pA typ. factor 2 / 10 °C</p> <p>± 120 pA (adjustable by offset potentiometer)</p> <p>9.1 nW (@ 10⁹ V/A, 1580 nm) 0.91 nW (@ 10¹⁰ V/A, 1580 nm)</p> <p>10 fW/$\sqrt{\text{Hz}}$ (@ 1580 nm, 100 Hz)</p>
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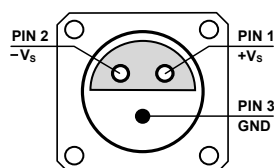
Ultra-Low Noise 2 kHz Photoreceiver with InGaAs-PIN Photodiode

Specifications (continued)

Detector	Detector Active area Spectral range Max. sensitivity	InGaAs-PIN photodiode Ø 0.5 mm 900 – 1700 nm 1.1 A/W typ. (@ 1580 nm)
Output	Output voltage range Output impedance Max. output current Output noise	–1.2 V ... +10 V (@ $\geq 100\text{ k}\Omega$ output load) 50 Ω (terminate with $\geq 100\text{ k}\Omega$ load) 30 mA (short-circuit proof) 0.75 mV RMS (5 mV peak-peak) typ. (@ 10^9 V/A , $\geq 100\text{ k}\Omega$ load, no signal on detector, measurement bandwidth 8 KHz)
Optical Input Connector	Material FST flange Material FST coupler ring	1.4305 stainless steel, nickel-plated 1.4305 stainless steel, glass bead blasted
Power Supply	Supply voltage Supply current	$\pm 15\text{ V}$ ($\pm 14.5\text{ V}$... $\pm 16.5\text{ V}$) +32 mA / –25 mA (depends on operating conditions, recommended power supply capability min. $\pm 100\text{ mA}$)
Case	Weight Material	220 g (0.49 lbs) PWPR-2K-IN-FST incl. coupler ring AlMg4.5Mn, nickel-plated
Temperature Range	Storage temperature Operating temperature	–30 °C ... +85 °C 0 °C ... +50 °C

Absolute Maximum Ratings	Optical input power (CW) Power supply voltage	10 mW $\pm 20\text{ V}$
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Connectors	Input Output Power supply	1.035"-40 threaded flange for free space applications and for use with various types of optical standard accessories BNC jack (female) LEMO® series 1S, 3-pin fixed socket (mating plug type: FFA.1S.303.CLAC52)
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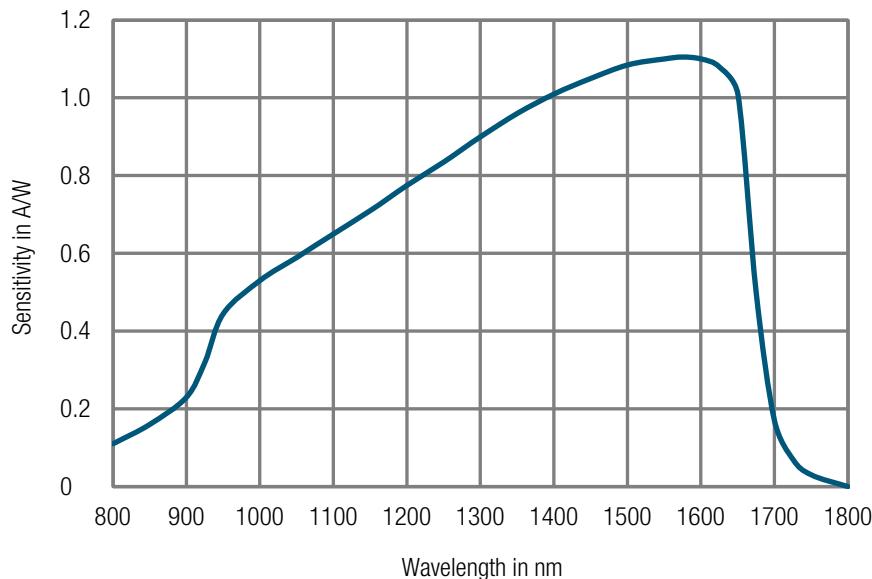
Pin 1: +15 V
Pin 2: –15 V
Pin 3: GND

Scope of Delivery	PWPR-2K-IN, internally threaded coupler ring, LEMO® 3-pin connector, datasheet, transport package
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Ordering Information	PWPR-2K-IN-FST 1.035"-40 threaded flange for free space applications and for use with various types of optical standard accessories
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Ultra-Low Noise 2 kHz Photoreceiver with InGaAs-PIN Photodiode

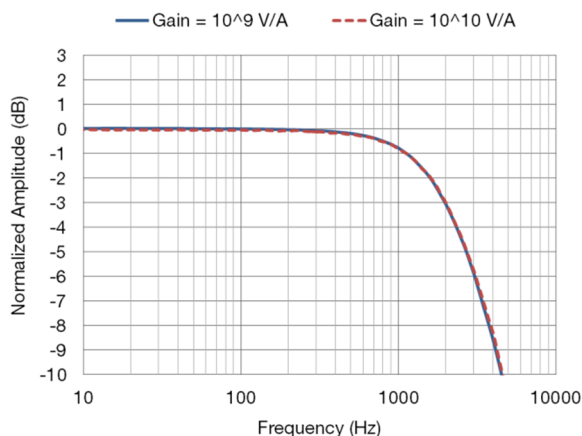
Spectral Responsivity



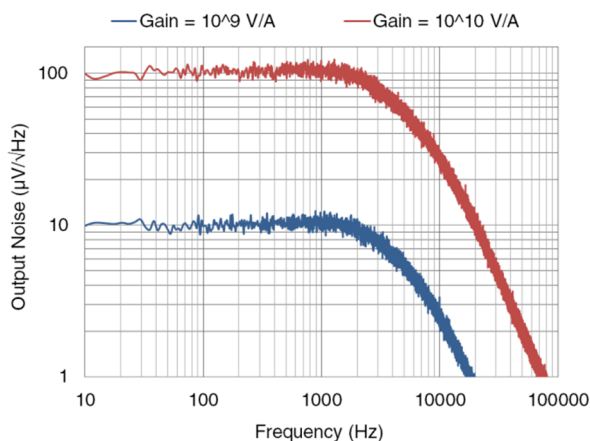
DB-Sens-PWPR-2K-IN_R02

Typical Performance Characteristics

Frequency Response



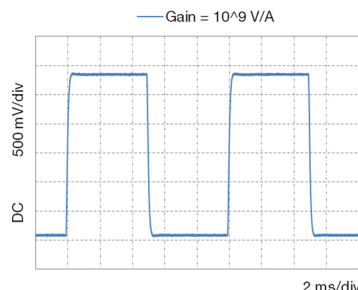
Output Noise



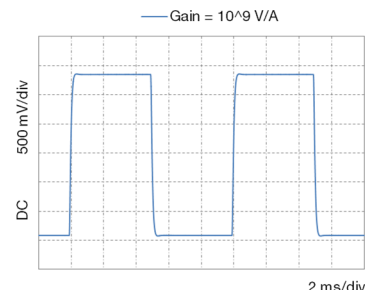
Ultra-Low Noise 2 kHz Photoreceiver with InGaAs-PIN Photodiode

Typical Performance
Characteristics (continued)

Step Signal Response @ 2500 pW (p-p, 1550 nm)

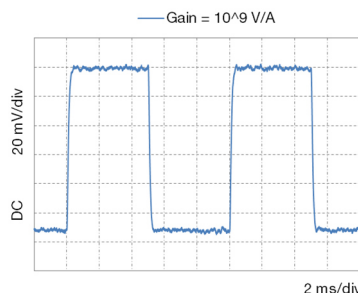


acquisition without averaging

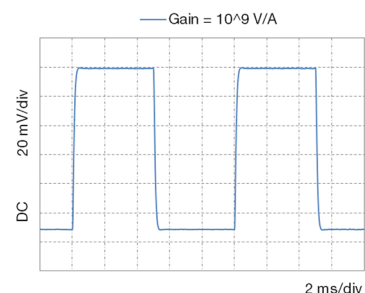


acquisition with 64x averaging

Step Signal Response @ 100 pW (p-p, 1550 nm)

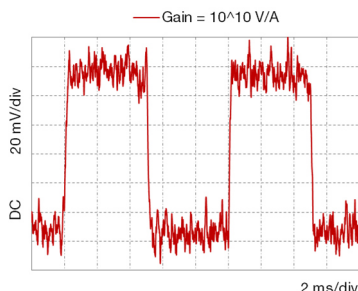


acquisition without averaging

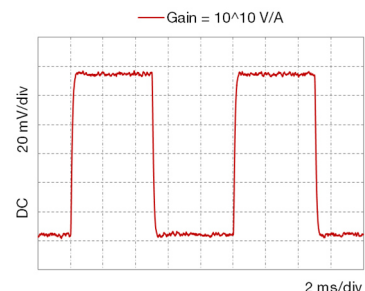


acquisition with 64x averaging

Step Signal Response @ 10 pW (p-p, 1550 nm)



acquisition without averaging

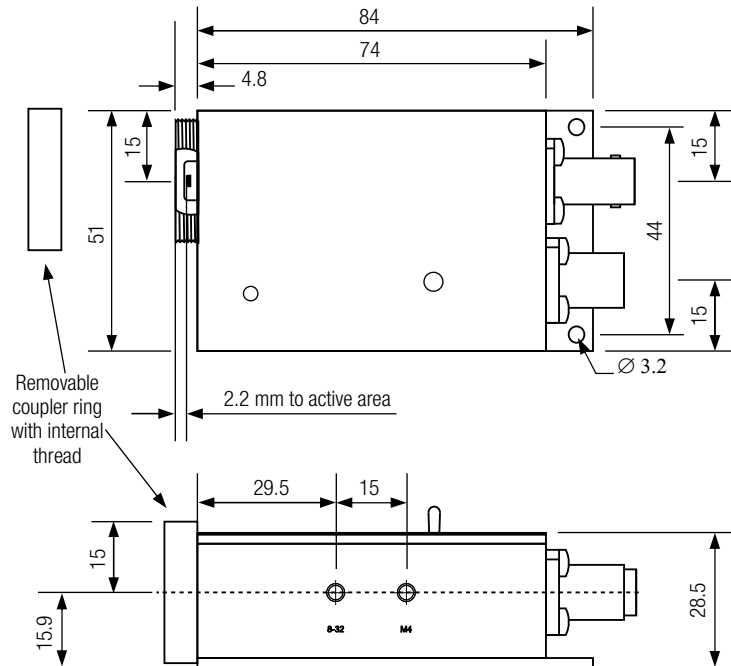


acquisition with 64x averaging

Ultra-Low Noise 2 kHz Photoreceiver with InGaAs-PIN Photodiode

Dimensions

PWPR-2K-IN-FST



DZ-PWPR-2K-FST_R02

all dimensions in mm unless otherwise noted

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